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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/516,703	12/02/2004	Hisao Sato	08228/061001	6746	
22511 . OSHA LIANG	7590 09/12/200 L.L.P.	7	EXAMINER		
1221 MCKINNEY STREET SUITE 2800			TRAN, TAN N		
HOUSTON, T	X 77010	·	ART UNIT	PAPER NUMBER	
			2826		
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			MAIL DATE	DELIVERY MODE	
			09/12/2007	PAPER	

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

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		Application No.	Applicant(s)	<del></del>
Office Action Summary		10/516,703	SATO ET AL.	
		Examiner	· Art Unit	
		TAN N. TRAN	2826	•
Period fo	The MAILING DATE of this communication app or Reply	pears on the cover sheet wit	h the correspondence addre	:ss
WHIC - Exte after - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR REPLY CHEVER IS LONGER, FROM THE MAILING DANSIONS of time may be available under the provisions of 37 CFR 1.13 SIX (6) MONTHS from the mailing date of this communication. O period for reply is specified above, the maximum statutory period vere to reply within the set or extended period for reply will, by statute, reply received by the Office later than three months after the mailing ed patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNIC 36(a). In no event, however, may a re vill apply and will expire SIX (6) MONT , cause the application to become ABA	ATION. ply be timely filed  HS from the mailing date of this comm NDONED (35 U.S.C. § 133).	
Status				
	This action is <b>FINAL</b> . 2b) This Since this application is in condition for allower	action is non-final. nce except for formal matte	, :	erits is
	closed in accordance with the practice under E	ex parte Quayle, 1935 C.D.	11, 453 O.G. 213.	•
Disposit	ion of Claims	,		
5)⊠ 6)⊠	Claim(s) 1-22 is/are pending in the application.  4a) Of the above claim(s) 11-17,19 and 21 is/are Claim(s) 3-9,18 and 20 is/are allowed.  Claim(s) 1,2,10 and 22 is/are rejected.  Claim(s) is/are objected to.  Claim(s) are subject to restriction and/or	re withdrawn from consider	ation.	·
Applicati	ion Papers			•
10)	The specification is objected to by the Examine The drawing(s) filed on is/are: a) access Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the Examine	epted or b)  objected to b drawing(s) be held in abeyand ion is required if the drawing(s	ee. See 37 CFR 1.85(a). s) is objected to. See 37 CFR	
Priority u	under 35 U.S.C. § 119			
a)	Acknowledgment is made of a claim for foreign  All b) Some * c) None of:  1. Certified copies of the priority documents  2. Certified copies of the priority documents  3. Copies of the certified copies of the priority application from the International Bureau  See the attached detailed Office action for a list	s have been received. s have been received in Ap rity documents have been r u (PCT Rule 17.2(a)).	plication No eceived in this National Sta	age ,
Attachmen	ıt(s)			
2) Notice 3) Information	te of References Cited (PTO-892) te of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO/SB/08) tr No(s)/Mail Date 04/12/07.	Paper No(s)	nmary (PTO-413) /Mail Date ormal Patent Application	

Application/Control Number: 10/516,703.

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#### **DETAILED ACTION**

## Claim Rejections - 35 USC § 103

1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1,2,10,22 rejected under 35 U.S.C. 103(a) as being unpatentable over Ozaki et al. (JP-2000-299532) in view of Nagahama (7,095,051).

With regard to claims 1,10, Ozaki et al. disclose a substrate; a first superlattice layer 4 which is formed above the substrate and in which an n-type AlGaN layer and an n-type GaN layer are alternately layered; a multiple quantum well layer 6 which is formed above the first superlattice layer 4 and in which a GaN-based quantum well layer and a GaN-based quantum barrier layer are alternately layered; and a second superlattice layer 9 which is formed above the multiple quantum well layer 6 and in which a p-type AlGaN layer and a p-type GaN layer are alternately layered. (Note lines 1-7, paragraph 0067, page 13; lines 1-6, paragraph 0069, page 13; lines 1-7, paragraph 0072, page 14, fig. 1 of Ozaki et al.).

Ozaki et al. does not disclose the multiple quantum well layer having AlInGaN well layer and an AlInGaN barrier layer are alternately layered.

However, Nagahama discloses the multiple quantum well layer having AlGaInN well layer (1a, or 1b) and an AlGaInN barrier layer (2a,2b) are alternately layered. (Note figs. 7,15A,15B).

Therefore, it would have been obvious to one of ordinary skill in the art to form the Ozaki et al.'s device having the multiple quantum well layer having AlGaInN well layer and an AlGaInN barrier layer are alternately layered such as taught by Nagahama in order to enhance a high efficiency of the light emitting device.

With regard to claim 2, Ozaki et al. disclose a buffer layer, a first GaN-based layer 2 which is formed above the buffer layer, and an n-type GaN-based layer 3 which is formed above the first GaN-based layer 2 are provided between the substrate and the first superlattice layer 4; a second GaN-based layer 5 is provided between the first superlattice layer 4 and the multiple quantum well layer 6; and a p-type GaN layer 10 is provided above the second superlattice layer 9. (Note fig. 1 of Ozaki et al.).

With regard to claim 22, Ozaki et al. disclose an n electrode 21 which is connected to the n-type GaN-based layer 3; a p electrode 20 which is connected to the p-type GaN-based layer 10; and a power supply which applies a voltage between the n electrode 21 and the p electrode 20. (Note fig. 1 of Ozaki et al.).

#### Allowable Subject Matter

2. Claims 3-9,18,20 allowable over the prior art of record because none of these references disclose or can be combined to yield the claimed invention.

### Response to Amendment

3. Applicant's arguments with respect to claims 1,2,10,22 have been considered but are most in view of the new ground(s) of rejection.

#### Conclusion

- 4. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, THIS ACTION IS MADE FINAL. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a). A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.
- 5. Any inquiry concerning this communication or earlier communications from the examiner should be directed to TAN N. TRAN whose telephone number is (571) 272-1923. The examiner can normally be reached on 8:30-5:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, **PURVIS SUE** can be reached on (571) 272-1236. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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TT

Aug 2007

SUPERVISORY PATENT EXAMINER